

27C64

64K (8K x 8) CMOS EPROM

FEATURES

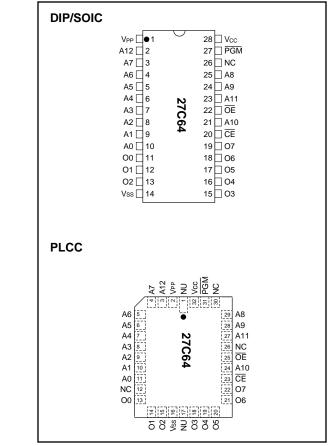
- High speed performance
 - 120 ns access time available
- · CMOS Technology for low power consumption
 - 20 mA Active current
 - 100 µA Standby current
- Factory programming available
- · Auto-insertion-compatible plastic packages
- · Auto ID aids automated programming
- Separate chip enable and output enable controls
- High speed "express" programming algorithm
- Organized 8K x 8: JEDEC standard pinouts
 - 28-pin Dual-in-line package
 - 32-pin PLCC Package
 - 28-pin SOIC package
 - Tape and reel
- · Available for the following temperature ranges
 - Commercial: 0°C to +70°C
 - Industrial: -40°C to +85°C

DESCRIPTION

The Microchip Technology Inc. 27C64 is a CMOS 64K bit (electrically) Programmable Read Only Memory. The device is organized as 8K words by 8 bits (8K bytes). Accessing individual bytes from an address transition or from power-up (chip enable pin going low) is accomplished in less than 120 ns. CMOS design and processing enables this part to be used in systems where reduced power consumption and high reliability are requirements.

A complete family of packages is offered to provide the most flexibility in applications. For surface mount applications, PLCC or SOIC packaging is available. Tape and reel packaging is also available for PLCC or SOIC packages.

PACKAGE TYPES



1.0 ELECTRICAL CHARACTERISTICS

1.1 <u>Maximum Ratings*</u>

Vcc and input voltages w.r.t. Vss0.6V to + 7.25V
VPP voltage w.r.t. Vss during programming0.6V to +14V
Voltage on A9 w.r.t. Vss0.6V to +13.5V
Output voltage w.r.t. Vss0.6V to Vcc +1.0V
Storage temperature65°C to +150°C
Ambient temp. with power applied65°C to +125°C

*Notice: Stresses above those listed under "Maximum Ratings" may cause permanent damage to the device. This is a stress rating only and functional operation of the device at those or any other conditions above those indicated in the operation listings of this specification is not implied. Exposure to maximum rating conditions for extended periods may affect device reliability.

TABLE 1-1: PIN FUNCTION TABLE

Name	Function
A0-A12	Address Inputs
CE	Chip Enable
ŌĒ	Output Enable
PGM	Program Enable
Vpp	Programming Voltage
00 - 07	Data Output
Vcc	+5V Power Supply
Vss	Ground
NC	No Connection; No Internal Connec- tions
NU	Not Used; No External Connection Is Allowed

TABLE 1-2: READ OPERATION DC CHARACTERISTICS

Vcc = +5V (±10%) Commercial: Tamb = 0°C to +70°C Industrial: Tamb = -40°C to +85°C											
Parameter	Part*	Status	Symbol	Min	Мах	Units	Conditions				
Input Voltages	all	Logic "1" Logic "0"	Vih Vil	2.0 -0.5	Vcc+1 0.8	V V					
Input Leakage	all		ILI	-10	10	μΑ	VIN = 0 to VCC				
Output Voltages	all	Logic "1" Logic "0"	Vон Vol	2.4	0.45	V V	IOH = -400 μA IOL = 2.1 mA				
Output Leakage	all	_	Ilo	-10	10	μA	VOUT = 0V to VCC				
Input Capacitance	all	_	CIN	_	6	pF	Vin = 0V; Tamb = 25°C; f = 1 MHz				
Output Capacitance	all	_	Соит		12	pF	Vout = 0V; Tamb = 25°C; f = 1 MHz				
Power Supply Current, Active	C I	TTL input TTL input	ICC1 ICC2	_	20 25	mA mA	VCC = 5.5V; VPP = VCC; f = 1 MHz; $\overline{OE} = \overline{CE} = VIL;$ IOUT = 0 mA; VIL = -0.1 to 0.8V; VIH = 2.0 to VCC; Note 1				
Power Supply Current, Standby	C I all	TTL input TTL input CMOS input	Icc(s) 		2 3 100	mA mA μA	<u>CE</u> = Vcc ± 0.2V				
IPP Read Current VPP Read Voltage	all all	Read Mode Read Mode	Ipp Vpp	Vcc-0.7	100 Vcc	μA V	VPP = 5.5V				

* Parts: C=Commercial Temperature Range; I =Industrial Temperature Range.

Note 1: Typical active current increases .5 mA per MHz up to operating frequency for all temperature ranges.

TABLE 1-3: READ OPERATION AC CHARACTERISTICS

	1 s: 1(C	VIH = 2.4V and VIL = 0.45V; VOH = 2.0V VOL = 0.8V 1 TTL Load + 100 pF 10 ns Commercial: Tamb = 0°C to +70°C Industrial: Tamb = -40°C to +85°C							'0°C				
_	2706	27C64-12 27C6		64-15 27C64-17		27C64-20		27C64-25					
Parameter	Sym	Min	Max	Min	Max	Min	Max	Min	Max	Min	Max	Units	Conditions
Address to Output Delay	tACC	_	120		150	_	170	_	200	_	250	ns	$\overline{CE} = \overline{OE} = VIL$
CE to Output Delay	tCE	_	120	_	150	_	170	_	200	_	250	ns	$\overline{OE} = VIL$
OE to Output Delay	tOE	_	65	_	70	_	70	_	75	_	100	ns	$\overline{CE} = VIL$
CE or OE to O/P High Impedance	tOFF	0	50	0	50	0	50	0	55	0	60	ns	
Output Hold from Address CE or OE, whichever occurs first	tOH	0		0		0		0		0		ns	

FIGURE 1-1: READ WAVEFORMS

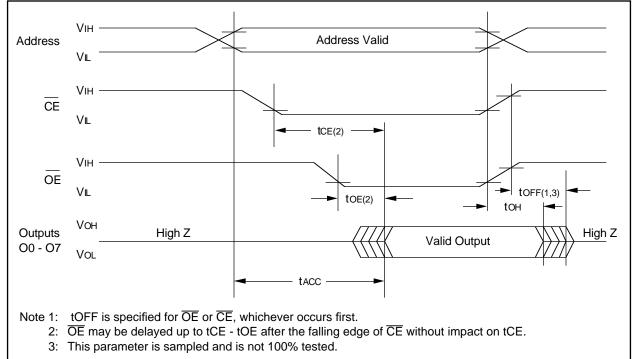


TABLE 1-4: PROGRAMMING DC CHARACTERISTICS

	Ambient Temperature: Tamb = $25^{\circ}C \pm 5^{\circ}C$ VCC = $6.5V \pm 0.25V$, VPP = VH = $13.0V \pm 0.25V$											
Parameter	Status	Symbol	Min	Max.	Units	Conditions						
Input Voltages	Logic"1" Logic"0"	Vih Vil	2.0 -0.1	Vcc+1 0.8	V V							
Input Leakage	_	١Lı	-10	10	μA	VIN = 0V to VCC						
Output Voltages	Logic"1" Logic"0"	Vон Vol	2.4 —	 0.45	V V	IOH = -400 μA IOL = 2.1 mA						
Vcc Current, program & verify		ICC2		20	mA	Note 1						
VPP Current, program	_	IPP2	_	25	mA	Note 1						
A9 Product Identification	—	Vн	11.5	12.5	V							

Note 1: VCC must be applied simultaneously or before VPP and removed simultaneously or after VPP.

TABLE 1-5: PROGRAMMING AC CHARACTERISTICS

for Program, Program Verify and Program Inhibit ModesAC Testing Waveform: VIH=2.4V and VIL=0.45V; VOH=2.0V; VOL=0.8V Ambient Temperature: Tamb=25°C ±5°C VCC= 6.5V ± 0.25V, VPP = VH = 13.0V ± 0.25V											
Parameter		Symbol	Min	Мах	Units	Remarks					
Address Set-Up Time		tAS	2		μs						
Data Set-Up Time		tDS	2		μs						
Data Hold Time		tDH	2	_	μs						
Address Hold Time		tAH	0	_	μs						
Float Delay (2)		tDF	0	130	ns						
Vcc Set-Up Time		tvcs	2	—	μs						
Program Pulse Width (1)		tPW	95	105	μs	100 μs typical					
CE Set-Up Time		tCES	2		μs						
OE Set-Up Time		tOES	2	_	μs						
VPP Set-Up Time		tVPS	2	_	μs						
Data Valid from OE		tOE	_	100	ns						

Note 1: For express algorithm, initial programming width tolerance is 100 μs $\pm 5\%.$

2: This parameter is only sampled and not 100% tested. Output float is defined as the point where data is no longer driven (see timing diagram).

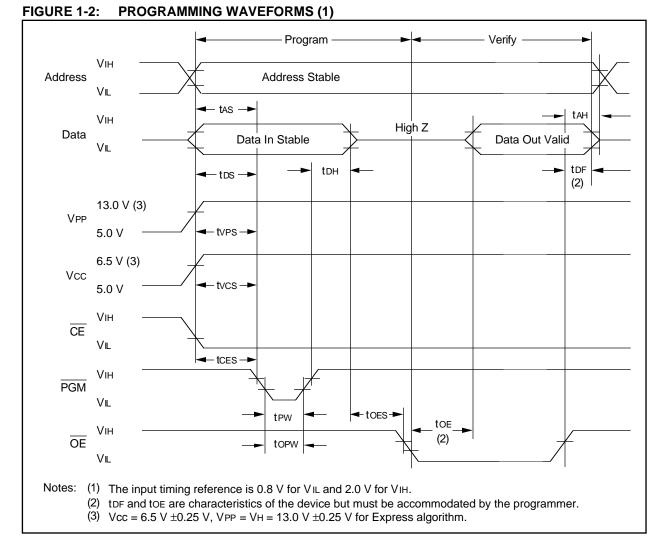


TABLE 1-6:	MODES
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Operation Mode	CE	ŌĒ	PGM	Vpp	A9	00 - 07
Read	VIL	VIL	Vih	Vcc	Х	Dout
Program	VIL	Vін	VIL	Vн	Х	DIN
Program Verify	VIL	VIL	Viн	Vн	Х	Dout
Program Inhibit	Viн	Х	х	Vн	Х	High Z
Standby	Viн	Х	х	Vcc	Х	High Z
Output Disable	VIL	Vін	Viн	Vcc	Х	High Z
Identity	VIL	VIL	Vih	Vcc	Vн	Identity Code

X = Don't Care

1.2 Read Mode

(See Timing Diagrams and AC Characteristics)

Read Mode is accessed when

- a) the CE pin is low to power up (enable) the chip
- b) the $\overline{\text{OE}}$ pin is low to gate the data to the output pins

For Read operations, if the addresses are stable, the address access time (tACC) is equal to the delay from \overline{CE} to output (tCE). Data is transferred to the output after a delay from the falling edge of \overline{OE} (tOE).

1.3 Standby Mode

The standby mode is defined when the \overline{CE} pin is high (VIH) and a program mode is not defined.

When these conditions are met, the supply current will drop from 20 mA to 100 $\mu A.$

1.4 Output Enable

This feature eliminates bus contention in microprocessor-based systems in which multiple devices may drive the bus. The outputs go into a high impedance state when the following condition is true:

• The OE and PGM pins are both high.

1.5 <u>Erase Mode (U.V. Windowed</u> <u>Versions)</u>

Windowed products offer the capability to erase the memory array. The memory matrix is erased to the all 1's state when exposed to ultraviolet light. To ensure complete erasure, a dose of 15 watt-second/cm² is required. This means that the device window must be placed within one inch and directly underneath an ultraviolet lamp with a wavelength of 2537 Angstroms, intensity of 12,000 μ W/cm² for approximately 20 minutes.

1.6 Programming Mode

The Express Algorithm has been developed to improve the programming throughput times in a production environment. Up to ten 100-microsecond pulses are applied until the byte is verified. No overprogramming is required. A flowchart of the express algorithm is shown in Figure 1-3.

Programming takes place when:

- a) Vcc is brought to the proper voltage,
- b) VPP is brought to the proper VH level,
- c) the \overline{CE} pin is low,
- d) the \overline{OE} pin is high, and
- e) the $\overline{\text{PGM}}$ pin is low.

Since the erased state is "1" in the array, programming of "0" is required. The address to be programmed is set via pins A0-A12 and the data to be programmed is presented to pins O0-O7. When data and address are stable, \overline{OE} is high, \overline{CE} is low and a low-going pulse on the \overline{PGM} line programs that location.

1.7 <u>Verify</u>

After the array has been programmed it must be verified to ensure all the bits have been correctly programmed. This mode is entered when all the following conditions are met:

- a) Vcc is at the proper level,
- b) VPP is at the proper VH level,
- c) the \overline{CE} line is low,
- d) the PGM line is high, and
- e) the \overline{OE} line is low.

1.8 Inhibit

When programming multiple devices in parallel with different data, only \overline{CE} or \overline{PGM} need be under separate control to each device. By pulsing the \overline{CE} or \overline{PGM} line low on a particular device in conjunction with the \overline{PGM} or \overline{CE} line low, that device will be programmed; all other devices with \overline{CE} or \overline{PGM} held high will not be programmed with the data, although address and data will be available on their input pins (i.e., when a high level is present on \overline{CE} or \overline{PGM}); and the device is inhibited from programming.

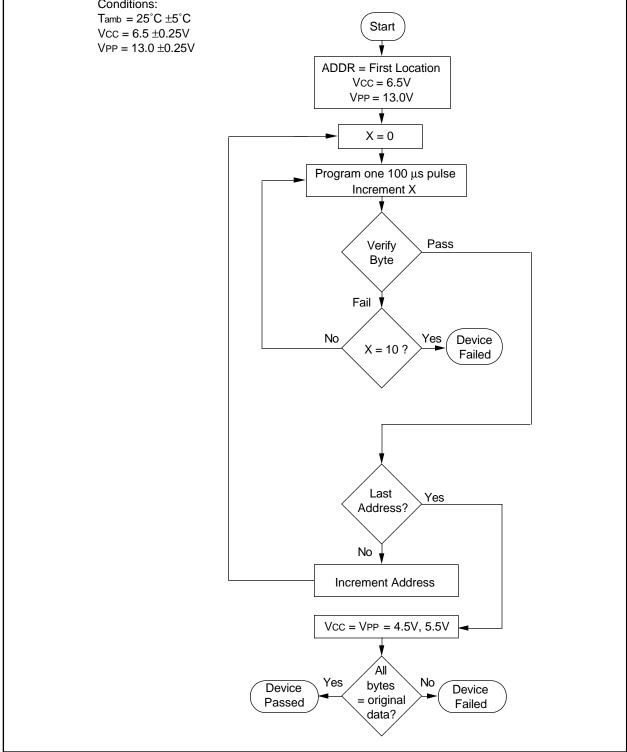
1.9 Identity Mode

In this mode, specific data is output which identifies the manufacturer as Microchip Technology Inc. and device type. This mode is entered when Pin A9 is taken to VH (11.5V to 12.5V). The \overline{CE} and \overline{OE} lines must be at VIL. A0 is used to access any of the two non-erasable bytes whose data appears on O0 through O7.

Pin —	Input	Output								
Identity	A0	0 7	0 6	0 5	0 4	0 3	0 2	0 1	0 0	H e x
Manufacturer Device Type*	VIL VIH	0 0	0 0	1 0	0 0	1 0	0 0	0 1	1 0	29 02

* Code subject to change





27C64 Product Identification System

To order or to obtain information, e.g., on pricing or delivery, please use the listed part numbers, and refer to the factory or the listed sales offices.

